## NSN 5962-01-126-5112

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-126-5112 **Body Length:** 1.260 inches **Body Width:** Between 0.350 inches and 0.390 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 750.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and hermetically sealed and monolithic and electrically alterable and w/clock and bidirectional **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 19 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -35.0 volts power source and 3.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 07187-4045271 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 22 printed circuit Shelf Life:

Yes - demil/mli

**Unit Of Measure:** 

**Demilitarization:** 

N/a

## NSN 5962-01-126-5112

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0